NSN 5961-01-337-5005

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-337-5005 **Inclosure Material:** Plastic or glass **Overall Length:** Between 0.315 inches and 0.355 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.165 inches and 0.180 inches **Function For Which Designed:** Transient suppressor **End Application:** 6625-01-212-3585 instrument controller **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 35.1 breakdown voltage, dc and 42.9 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes drain current nanoamperes **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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